NSN 5961-01-294-4715

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Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-294-4715 **Inclosure Material:** Plastic or ceramic **Overall Length:** Between 0.660 inches and 0.785 inches **Component Name And Quantity:** 5 transistor **Mounting Method: Terminal Features Provided:** Burn in **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 15.0 collector to emitter voltage/static/base open all transistor and 20.0 collector to base voltage/static/emitter open all transistor and 5.0 emitter to base voltage, static, collector open all transistor **Current Rating Per Characteristic:** 50.00 milliamperes zero-gate-voltage source current blank all transistor **Power Rating Per Characteristic:** 300.0 milliwatts small-signal input power, common-collector preset all transistor **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Special Features:** All transistor junction pattern arrangement: npn **Terminal Type And Quantity:** 14 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: